8-Bit Addressable Latch

The SN74LS259 is a high-speed 8-Bit Addressable Latch designed for general purpose storage applications in digital systems. It is a multifunctional device capable of storing single line data in eight addressable latches, and also a 1-of-8 decoder and demultiplexer with active HIGH outputs. The device also incorporates an active LOW common Clear for resetting all latches, as well as, an active LOW Enable.

- Serial-to-Parallel Conversion
- Eight Bits of Storage With Output of Each Bit Available
- Random (Addressable) Data Entry
- Active High Demultiplexing or Decoding Capability
- Easily Expandable
- Common Clear

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
VCC	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
ІОН	IOH Output Current – High			-0.4	mA
I _{OL} Output Current – Low				8.0	mA



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LOW POWER SCHOTTKY



PLASTIC N SUFFIX CASE 648



SOIC D SUFFIX CASE 751B



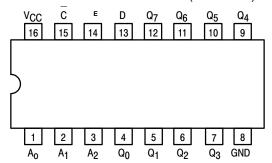
SOEIAJ M SUFFIX CASE 966

ORDERING INFORMATION

Device	Package	Shipping	
SN74LS259N	16 Pin DIP	2000 Units/Box	
SN74LS259D	SOIC-16	38 Units/Rail	
SN74LS259DR2	SOIC-16	2500/Tape & Reel	
SN74LS259M	SOEIAJ-16	See Note 1	
SN74LS259MEL	SOEIAJ-16	See Note 1	

 For ordering information on the EIAJ version of the SOIC package, please contact your local ON Semiconductor representative.

CONNECTION DIAGRAM DIP (TOP VIEW)

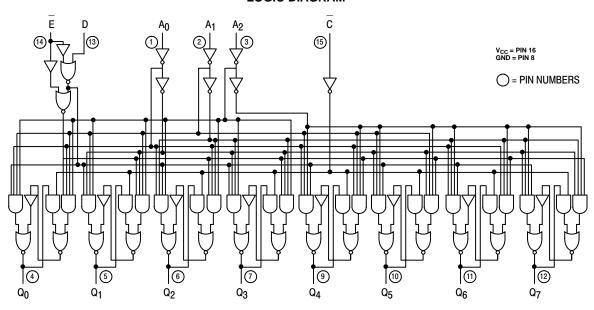


		LOADING	(Note a)
PIN NAMES	;	HIGH	LOW
A ₀ , A ₁ , A ₂	Address Inputs	0.5 U.L.	0.25 U.L.
<u>D</u>	Data Input	0.5 U.L.	0.25 U.L.
<u>E</u>	Enable (Active LOW) Input	1.0 U.L.	0.5 U.L.
С	Clear (Active LOW) Input	0.5 U.L.	0.25 U.L.
Q ₀ - Q ₇	Parallel Latch Outputs	10 U.L.	5 U.L.

NOTES:

a) 1 TTL Unit Load (U.L.) = 40 μ A HIGH/1.6 mA LOW.

LOGIC DIAGRAM



FUNCTIONAL DESCRIPTION

The SN74LS259 has four modes of operation as shown in the mode selection table. In the addressable latch mode, data on the Data line (D) is written into the addressed latch. The addressed latch will follow the data input with all non-addressed latches remaining in their previous states. In the memory mode, all latches remain in their previous state and are unaffected by the Data or Address inputs.

In the one-of-eight decoding or demultiplexing mode, the addressed output will follow the state of the D input with all

other inputs in the LOW state. In the clear mode all outputs are LOW and unaffected by the address and data inputs.

When operating the SN74LS259 as an addressable latch, changing more then one bit of the address could impose a transient wrong address. Therefore, this should only be done while in the memory mode.

The truth table below summarizes the operations.

MODE SELECTION

Ε	С	MODE
L	Н	Addressable Latch
Н	Н	Memory
L	L	Active HIGH Eight-Channel Demultiplexer
Н	L	Clear

TRUTH TABLE PRESENT OUTPUT STATES

_	_													
С	Ε	D	A ₀	Α1	A ₂	Q_0	Q_1	Q_2	Q_3	Q_4	Q_5	Q_6	Q_7	MODE
L	Н	Χ	Χ	Χ	Χ	L	L	L	L	L	L	L	L	Clear
L	L	L	L	L	L	L	L	L	L	L	L	L	L	Demultiplex
L	L	Н	L	L	L	Н	L	L	L	L	L	L	L	
L	L	L	Н	L	L	L	L	L	L	L	L	L	L	
L	L	Н	Н	L	L	L	Н	L	L	L	L	L	L	
•	•	•		•					•					
•	•	•		•					•					
•	•	•		•					•					
•	•	•		•					•					
•	•	•		•					•					
L	L	Н	Н	Н	Н	L	L	L	L	L	L	L	Н	
Н	Н	Χ	Χ	Χ	Χ	Q_{N-1}							<u> </u>	Memory
Н	I	ı	L	L	L	L	Q_{N-1}	Q_{N-1}	Q _{N-1} -					Addressable
Н	L	Н	L	L	L	Н	Q_{N-1}	Q _{N-1} -						Latch
Н	L	L	Н	L	L	Q_{N-1}	L	Q _{N-1} -					-	
Н	L	Н	Н	L	L	Q_{N-1}	Н	Q _{N-1} -						
•	•	•		•					•					
•	•	•		•					•					
•	•	•		•					•					
•	•	•		•					•					
•	•	•		•					•			_		
Н	L	L	Н	Н	H	Q_{N-1}					→	Q_{N-1}	L	
Н	L	Н	Н	Н	Н	Q_{N-1}					-	Q_{N-1}	Н	

X = Don't Care Condition L = LOW Voltage Level H = HIGH Voltage Level Q_{N-1} = Previous Output State

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

			Limits				
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions
VIH	Input HIGH Voltage	2.0			V	Guaranteed Inpu All Inputs	t HIGH Voltage for
V _{IL}	Input LOW Voltage			0.8	V	Guaranteed Inpu All Inputs	t LOW Voltage for
VIK	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} = -18 mA	
Vон	Output HIGH Voltage	2.7	3.5		V	$V_{CC} = MIN, I_{OH} = MAX, V_{IN} = V_{IH}$ or V_{IL} per Truth Table	
.,	0		0.25	0.4	V	I _{OL} = 4.0 mA	V _{CC} = V _{CC} MIN,
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 8.0 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table
1	lament I II Cl I Command			20	μΑ	V _{CC} = MAX, V _{IN}	= 2.7 V
lН	Input HIGH Current			0.1	mA	V _{CC} = MAX, V _{IN} = 7.0 V	
IIL	Input LOW Current			-0.4	mA	V _{CC} = MAX, V _{IN} = 0.4 V	
los	Short Circuit Current (Note 2)	-20		-100	mA	V _{CC} = MAX	
lcc	Power Supply Current			36	mA	V _{CC} = MAX	

^{2.} Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS ($T_A = 25$ °C, $V_{CC} = 5.0 \text{ V}$)

		Limits						
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
^t PLH ^t PHL	Turn-Off Delay, Enable to Output Turn-On Delay, Enable to Output		22 15	35 24	ns ns			
tPLH tPHL	Turn-Off Delay, Data to Output Turn-On Delay, Data to Output		20 13	32 21	ns ns	C _L = 15 pF		
tPLH tPHL	Turn-Off Delay, Address to Output Turn-On Delay, Address to Output		24 18	38 29	ns ns	- '		
tPHL	Turn-On Delay, Clear to Output		17	27	ns			

AC SET-UP REQUIREMENTS (T_A = 25°C, V_CC = 5.0 V)

		Limits			
Symbol	Parameter	Min	Тур	Max	Unit
t _S	Input Setup Time	20			ns
t _W	Pulse Width, Clear or Enable	15			ns
th	Hold Time, Data	5.0			ns
^t h	Hold Time, Address	20			ns

AC WAVEFORMS

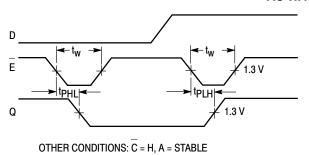


Figure 1. Turn-on and Turn-off Delays, Enable To Output and Enable Pulse Width

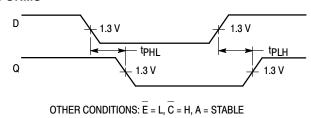


Figure 2. Turn-on and Turn-off Delays, Data to Output

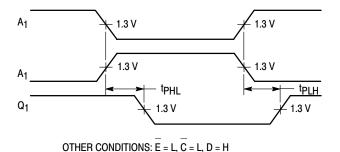
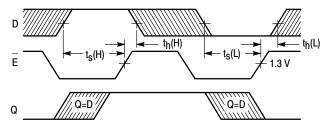
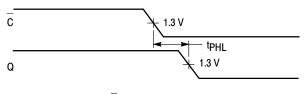


Figure 3. Turn-on and Turn-off Delays, Address to Output



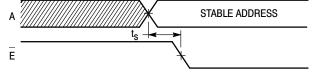
OTHER CONDITIONS: $\overline{C} = H$, A = STABLE

Figure 4. Setup and Hold Time, Data to Enable



OTHER CONDITIONS: E = H

Figure 5. Turn-on Delay, Clear to Output



OTHER CONDITIONS: C = H

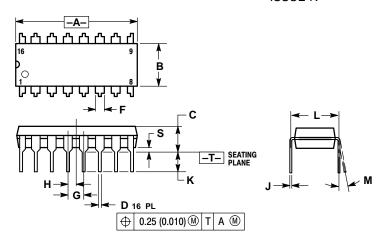
Figure 6. Setup Time, Address to Enable (See Notes 1 and 2)

NOTES:

- 1. The Address to Enable Setup Time is the time before the HIGH-to-LOW Enable transition that the Address must be stable so that the correct latch is addressed and the other latches are not affected.
- 2. The shaded areas indicate when the inputs are permitted to change for predictable output performance.

PACKAGE DIMENSIONS

N SUFFIX PLASTIC PACKAGE CASE 648-08 ISSUE R

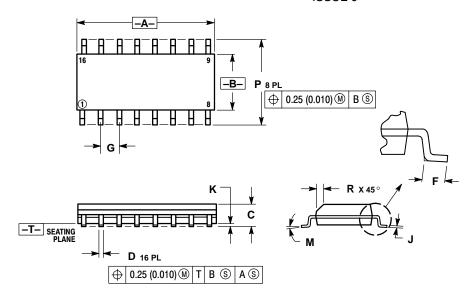


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIMETERS			
DIM	MIN	MAX	MIN	MAX		
Α	0.740	0.770	18.80	19.55		
В	0.250	0.270	6.35	6.85		
С	0.145	0.175	3.69	4.44		
D	0.015	0.021	0.39	0.53		
F	0.040	0.70	1.02	1.77		
G	0.100	BSC	2.54 BSC			
Н	0.050	BSC	1.27 BSC			
J	0.008	0.015	0.21	0.38		
K	0.110	0.130	2.80	3.30		
L	0.295	0.305	7.50	7.74		
М	0°	10°	0°	10 °		
S	0.020	0.040	0.51	1.01		

PACKAGE DIMENSIONS

D SUFFIX PLASTIC SOIC PACKAGE CASE 751B-05 **ISSUE J**



NOTES:

- NOTES:

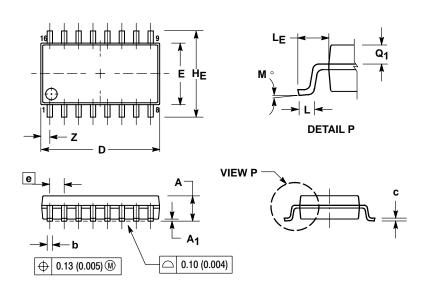
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INCHES				
DIM	MIN	MAX	MIN	MAX			
Α	9.80	10.00	0.386	0.393			
В	3.80	4.00	0.150	0.157			
С	1.35	1.75	0.054	0.068			
D	0.35	0.49	0.014	0.019			
F	0.40	1.25	0.016	0.049			
G	1.27	BSC	0.050 BSC				
J	0.19	0.25	0.008	0.009			
K	0.10	0.25	0.004	0.009			
M	0°	7°	0°	7°			
P	5.80	6.20	0.229	0.244			
R	0.25	0.50	0.010	0.019			

PACKAGE DIMENSIONS

M SUFFIX

SOEIAJ PACKAGE CASE 966-01 ISSUE O



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETER.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
 THE LEAD WIDTH DIMENSION (b) DOES NOT
- THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α		2.05		0.081	
Α ₁	0.05	0.20	0.002	0.008	
b	0.35	0.50	0.014	0.020	
С	0.18	0.27	0.007	0.011	
D	9.90	10.50	0.390	0.413	
E	5.10	5.45	0.201	0.215	
е	1.27	BSC	0.050 BSC		
HE	7.40	8.20	0.291	0.323	
L	0.50	0.85	0.020	0.033	
LE	1.10	1.50	0.043	0.059	
M	0 °	10°	0°	10°	
Q ₁	0.70	0.90	0.028	0.035	
Z		0.78		0.031	

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